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Substitute for form 1449B/PTO <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  Date Submitted: May 23, 2006  (use as many sheets as necessary)				<b>Complete if Known</b>	
				Application Number	10/577,398
				Filing Date	09/17/2004
				First Named Inventor	Koichi TAKEDA
				Group Art Unit	Unassigned
				Examiner Name	Unassigned
				Attorney Docket Number	016778-0507
Sheet	1	of	1		

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			

U.S. PATENT APPLICATION DOCUMENTS						
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		Serial Number	Kind Code <sup>2</sup> (if known)			

FOREIGN PATENT DOCUMENTS								
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		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.			T <sup>6</sup>
	B1	A.J. BHAVNAGARWALA et al., "The Impact of Intrinsic Device Fluctuations on CMOS SRAM Cell Stability," IEEE Journal of Solid-State Circuits, Vol. 36:4, April, 2001.			
	B2	H. SAKAKIBARA et al., "A 750 MHz Cache DRAM LSi with Speed Scalable Design and Programmable at-Speed Function-Array BIST," 2003 IEEE International Solid-State Circuits Conference			

Examiner Signature	/Son Mai/	Date Considered	06/25/2008
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Unique citation designation number. <sup>2</sup> See attached Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document.

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